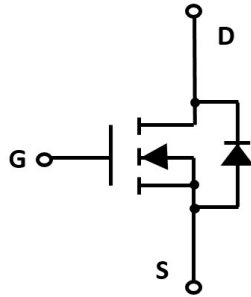
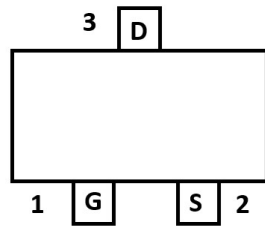
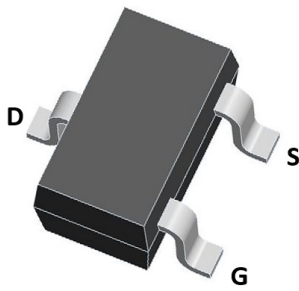


N-Channel Enhancement Mode Field Effect Transistor



SOT-323

Product Summary

- V_{DS} 100V
- I_D 200mA
- $R_{DS(ON)}$ (at $V_{GS}=10V$) $<5.0\Omega$
- $R_{DS(ON)}$ (at $V_{GS}=4.5V$) $<5.5\Omega$

General Description

- Trench Power MV MOSFET technology
- Voltage controlled small signal switch
- High density cell design for low $R_{DS(ON)}$
- Fast Switching Speed

Applications

- Small servo motor control
- Power MOSFET gate drivers
- Switching application

■ Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-source Voltage		V_{DS}	100	V
Gate-source Voltage		V_{GS}	± 20	V
Drain Current	$T_A=25^\circ\text{C}$ @ Steady State	I_D	200	mA
	$T_A=70^\circ\text{C}$ @ Steady State		160	
Pulsed Drain Current ^A		I_{DM}	800	mA
Total Power Dissipation @ $T_A=25^\circ\text{C}$		P_D	150	mW
Thermal Resistance Junction-to-Ambient @ Steady State ^B		$R_{\theta JA}$	833	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range		T_J, T_{STG}	$-55 \sim +150$	$^\circ\text{C}$

■ Ordering Information

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
BSS123W	F2	B123.	3000	30000	120000	7" reel



BSS123W

■ Electrical Characteristics (T_J=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} = 0V, I _D =250μA	100			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =100V, V _{GS} =0V			1	μA
Gate-Body Leakage Current	I _{GSS1}	V _{GS} = ±20V, V _{DS} =0V			± 100	nA
	I _{GSS2}	V _{GS} = ± 10V, V _{DS} =0V			± 50	nA
Gate Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D =250μA	1.0	1.8	2.5	V
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} = 10V, I _D =200mA		3.0	5.0	Ω
		V _{GS} = 4.5V, I _D =200mA		3.5	5.5	
Diode Forward Voltage	V _{SD}	I _S =200mA, V _{GS} =0V			1.2	V
Maximum Body-Diode Continuous Current	I _S				200	mA
Dynamic Parameters						
Input Capacitance	C _{iss}	V _{DS} =50V, V _{GS} =0V, f=1MHZ		32		pF
Output Capacitance	C _{oss}			10		
Reverse Transfer Capacitance	C _{rss}			7		
Switching Parameters						
Total Gate Charge	Q _g	V _{GS} =10V, V _{DS} =50V, I _D =0.2A		1.61		nC
Turn-on Delay Time	t _{D(on)}	V _{GS} =10V, V _{DD} =50V, I _D =0.2A, R _{GEN} =6Ω		1.8		ns
Turn-on Rise Time	t _r			9.2		
Turn-off Delay Time	t _{D(off)}			17.5		
Turn-off fall Time	t _f			7.6		

A. Pulse Test: Pulse Width≤300us, Duty cycle ≤2%.

B. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch.



■ Typical Performance Characteristics

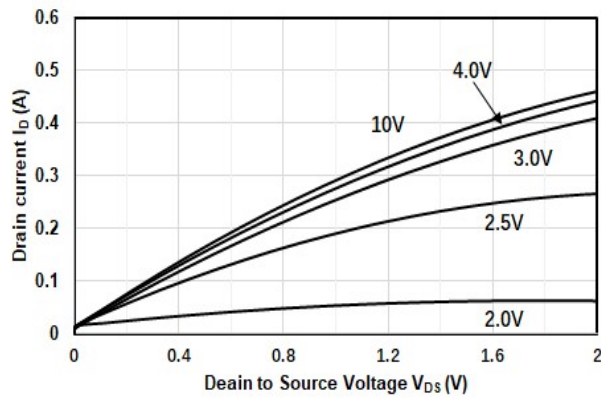


Figure1. Output Characteristics

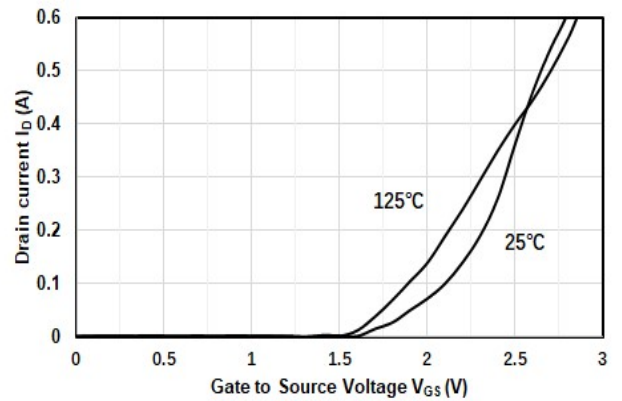


Figure2. Transfer Characteristics

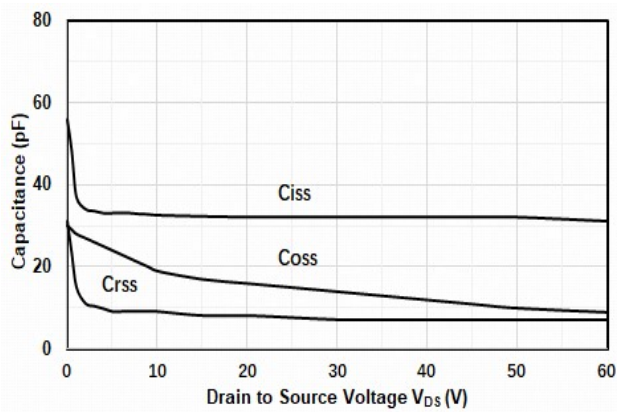


Figure3. Capacitance Characteristics

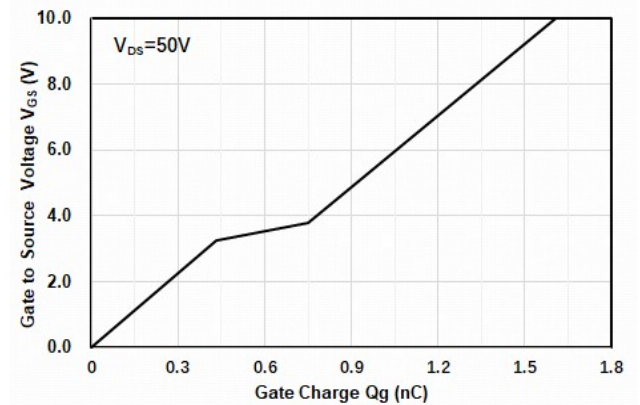


Figure4. Gate Charge

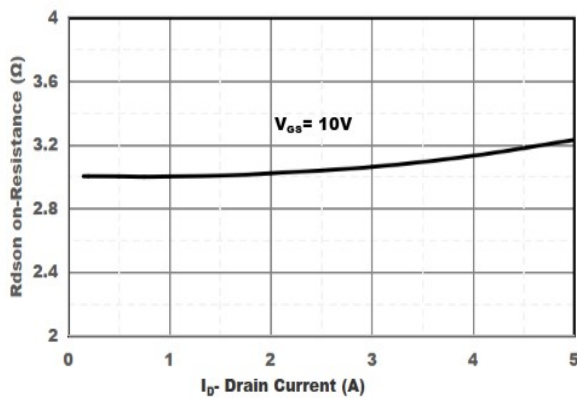


Figure5. Drain-Source on Resistance

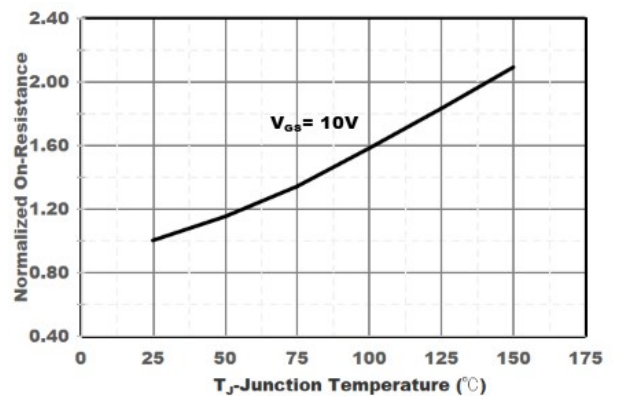


Figure6. Drain-Source on Resistance



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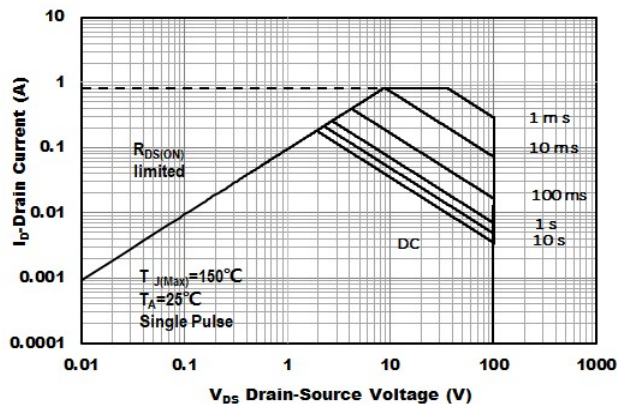


Figure7. Safe Operation Area

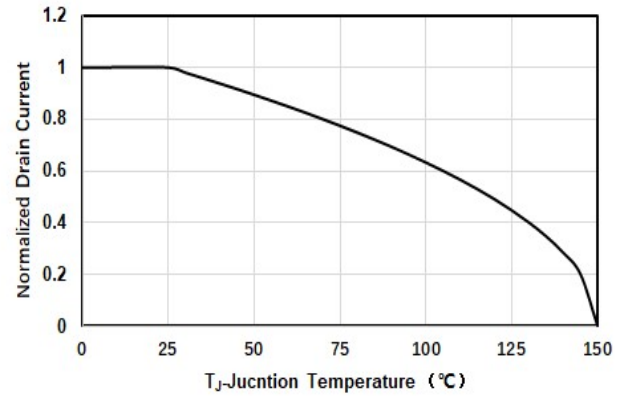
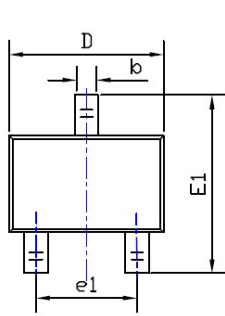


Figure8. Drain-Source Current

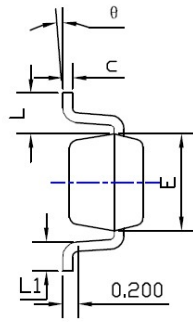


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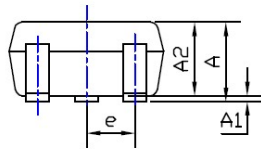
■ SOT-323 Package Information



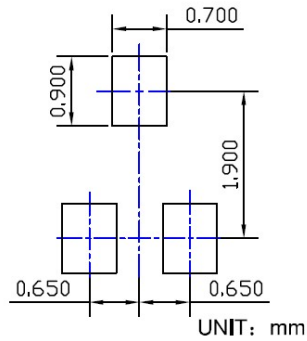
TOP VIEW



SIDE VIEW



SIDE VIEW



SUGGESTED SOLDER PAD LAYOUT

SYMBOL	DIMENSIONS			DIMENSIONS		
	INCHES			Millimeter		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.035	---	0.043	0.900	---	1.100
A1	0.000	---	0.004	0.000	---	0.100
A2	0.035	0.037	0.039	0.900	0.950	1.000
b	0.006	0.012	0.016	0.150	0.300	0.400
c	0.004	---	0.010	0.100	---	0.250
D	0.071	0.079	0.087	1.800	2.000	2.200
E	0.045	0.049	0.053	1.150	1.250	1.350
E1	0.085	0.091	0.096	2.150	2.300	2.450
e	0.026TYP			0.650TYP		
e1	0.047	0.051	0.055	1.200	1.300	1.400
L	0.021REF			0.525REF		
L1	0.010	0.014	0.018	0.260	0.360	0.460
θ	0°	---	8°	0°	---	8°

NOTE:

1. PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
2. TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
3. THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.



BSS123W

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